

## MGBR40U45C

Preliminary

DIODE

# DUAL MOS GATED BARRIER RECTIFIER

## DESCRIPTION

The UTC **MGBR40U45C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

## FEATURES

\* Ultra low forward voltage drop\* High switching speed

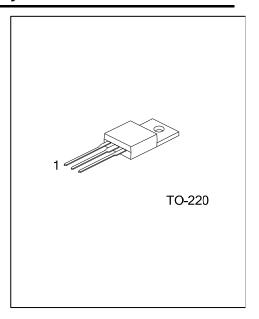
## SYMBOL

### ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR40U45CL-TA3-T	MGBR40U45CG-TA3-T	TO-220	Α	К	А	Tube	

#### Note: Pin Assignment: A: Anode, K: Cathode

MGBR40U45C <u>L-TA3-T</u>     (1)Pac	king Type	(1) T: Tube
(2)Pac	kage Type	(2) TA3: TO-220
(3)Lea	d Free	(3) L: Lead Free, G: Halogen Free



#### ■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T<sub>A</sub>=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%

Tor capacitance load, derate current by 2070.				
PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V <sub>RM</sub>	45	V
Working Peak Reverse Voltage		V <sub>RWM</sub>	45	V
Peak Repetitive Reverse Voltage		V <sub>RRM</sub>	45	V
Average Destified Output Current Per Device	Per Leg	- I <sub>O</sub>	20	А
Average Rectified Output Current Per Device	Total		40	А
Non-Repetitive Peak Forward Surge Current 8. Single Half Sine-Wave Superimposed on Rated		I <sub>FSM</sub>	360	А
Operating Junction Temperature		ΤJ	-65~+150	°C
Storage Temperature		T <sub>STG</sub>	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### THERMAL CHARACTERISTICS (PER LEG)

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ <sub>JC</sub>	2	°C/W

#### ■ ELECTRICAL CHARACTERISTICS (PER LEG) (T<sub>A</sub> =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V <sub>(BR)R</sub>	I <sub>R</sub> =0.50mA	45			V
Forward Voltage Drop		I <sub>F</sub> =20A, T <sub>J</sub> =25°C			0.45	V
		I <sub>F</sub> =20A, TJ=125°C			0.40	V
Leakage Current (Note 1)	RM	V <sub>R</sub> =45V, T <sub>J</sub> =25°C			500	μA
		V <sub>R</sub> =45V, T <sub>J</sub> =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



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